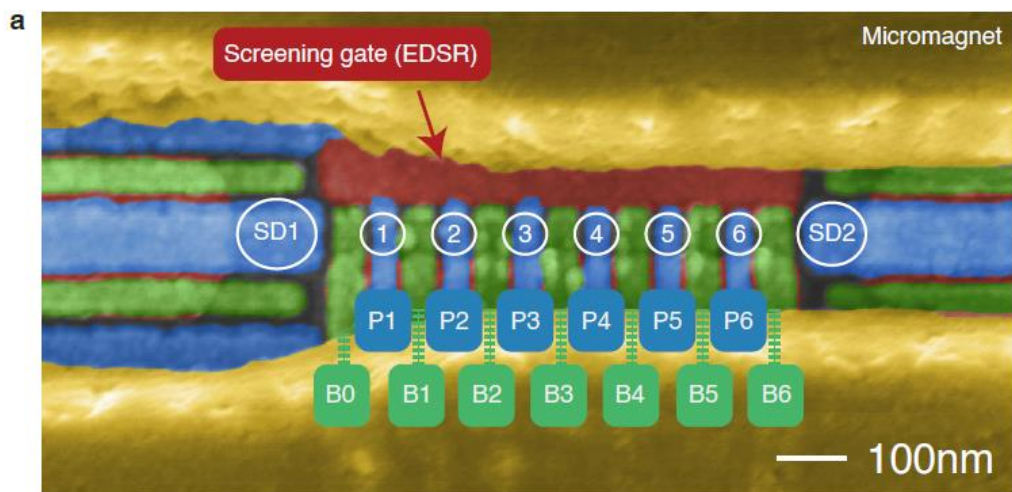




Universal control of a six-qubit quantum processor in silicon

Stephan G.J. Philips^{*1}, Mateusz T. Maździk^{*1}, Sergey V. Amitonov¹, Sander L. de Snoo¹, Maximilian Russ¹, Nima Kalhor¹, Christian Volk¹, William I.L. Lawrie¹, Delphine Brousse², Larysa Tryputen², Brian Paquelet Wuetz¹, Amir Sammak², Menno Veldhorst¹, Giordano Scappucci¹, and Lieven M.K. Vandersypen^{† 1}

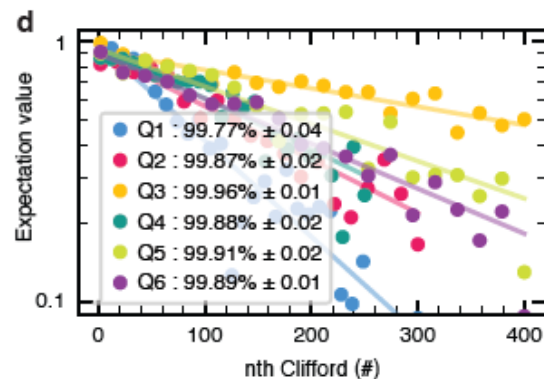


c

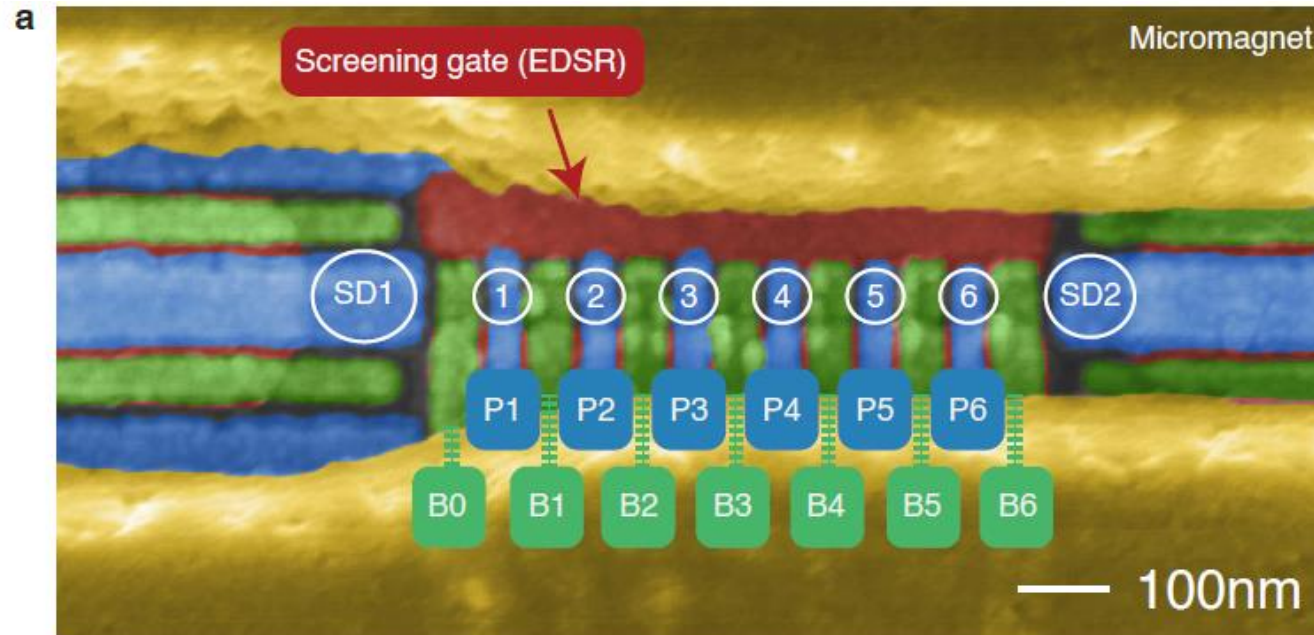
Qubit	T_2^* (us)	T_2^H (us)	Vis(%)
1	3.0 ± 0.2	14.0 ± 3.2	95.5
2	2.5 ± 0.1	21.1 ± 6.7	95.5
3	3.7 ± 0.3	40.1 ± 4.5	98
4	3.7 ± 0.3	37.2 ± 3.8	97
5	5.9 ± 0.4	44.7 ± 8.2	93.5
6	5.1 ± 0.4	26.7 ± 4.8	96.5

h

Qubits	Fidelity (%)	Concurrence (%)
1-2	89.2 ± 2.2	86.7 ± 3.2
2-3	90.1 ± 2.2	83.9 ± 3.8
3-4	88.3 ± 3.6	87.9 ± 5.0
4-5	95.6 ± 2.0	94.9 ± 3.2
5-6	94.1 ± 1.4	90.6 ± 3.6

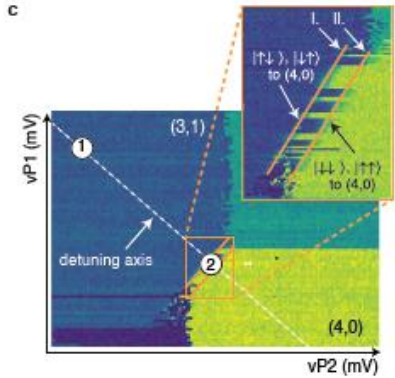


Device

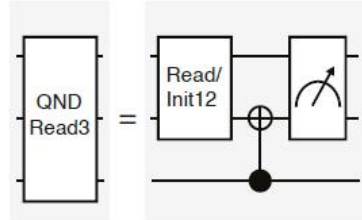


- 6 dots – can accumulate with $1e^-$, but choose to accumulate outer dots (1,6) with 3 electrons
- 2 sensor dots on end of array
- Approach:
 - screening (“slit”) gate to avoid accumulation everywhere under gates on top
 - Then make 2 layers of plunger/barrier
- Isolating dielectric: AlO from ALD, gates made from Ti/Pd, SiGe/Si/SiGe heterostructure for 2DEG
- Read-out with charge sensors+tank circuit

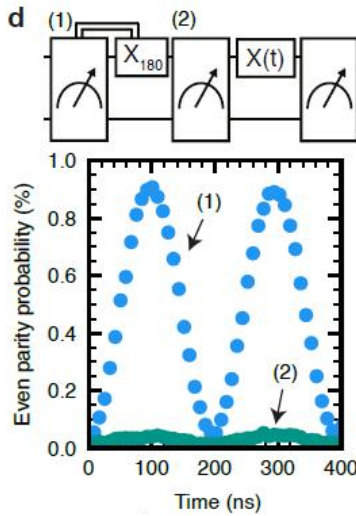
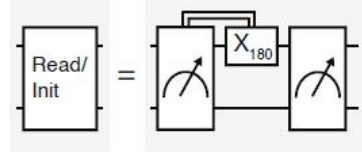
Initialization/Measurements:



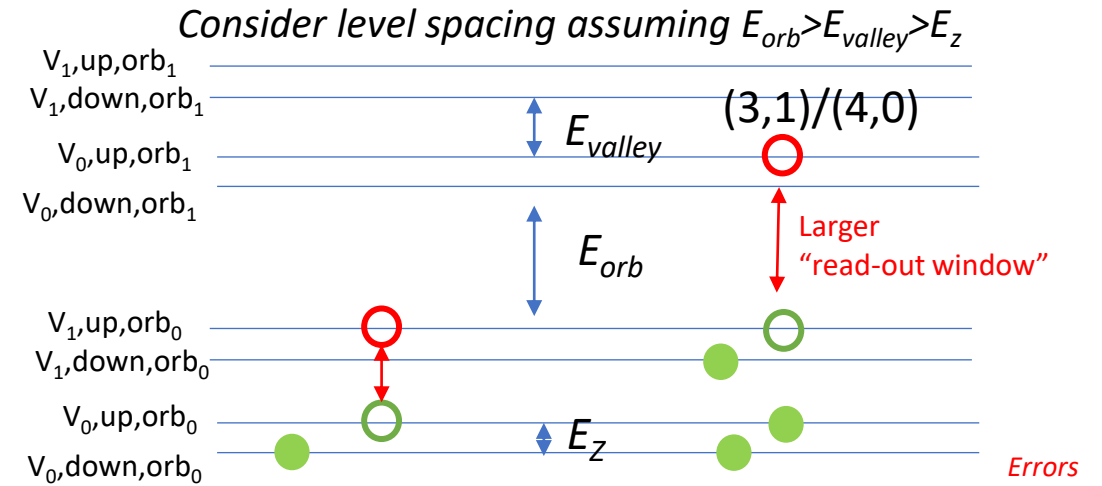
QND measurement qubit 3



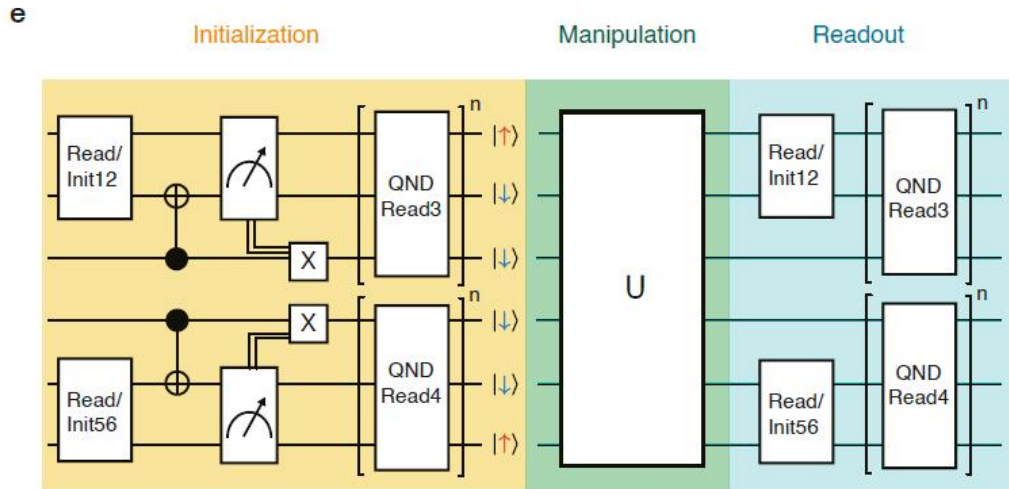
Real-time feedback initialization



Why 3,1 -> 4,0:

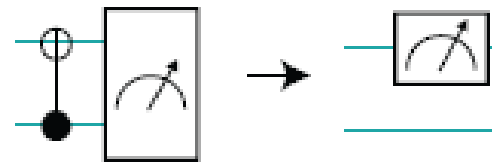


Spin-blockade read-out
 -> get parity between outer two dots (1,2 or 5,6)

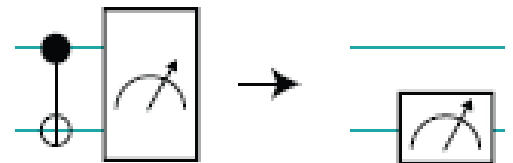


g

ZI measurement with ZZ operator



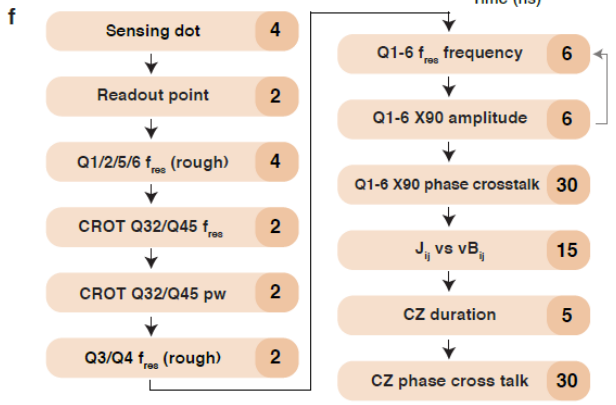
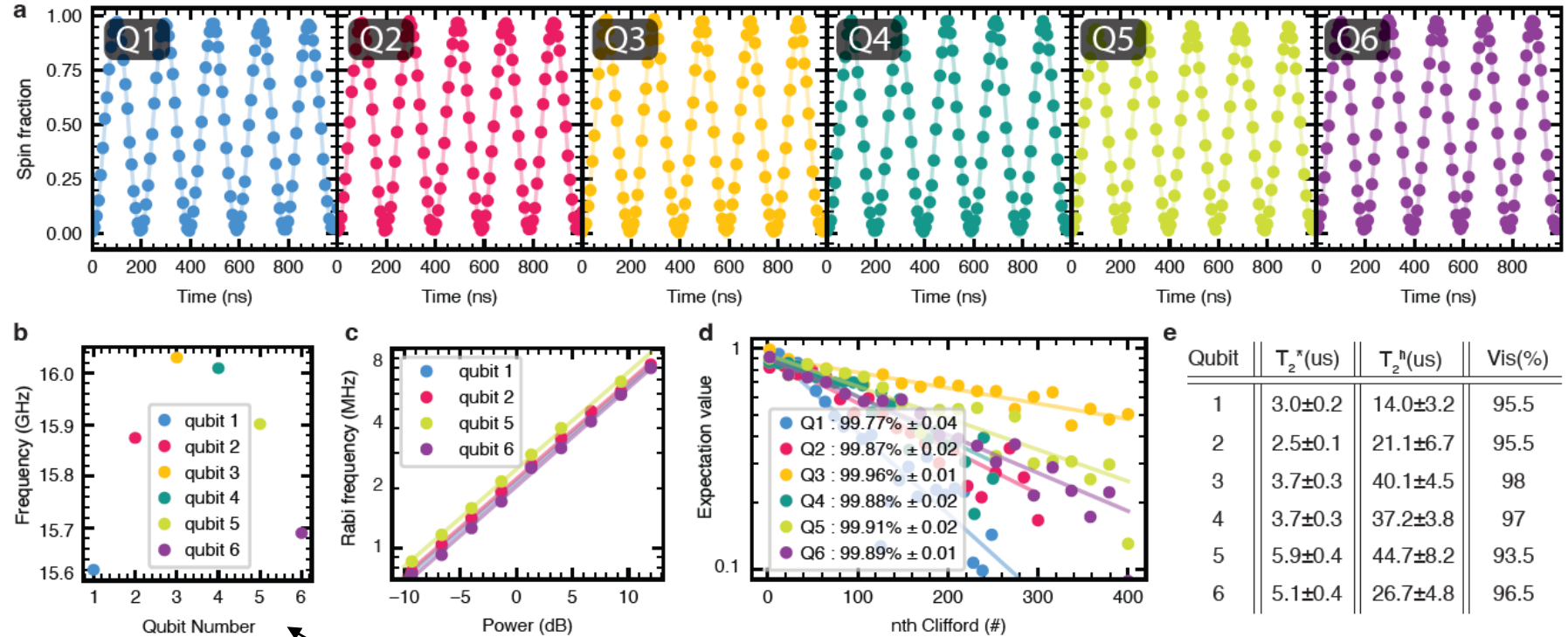
IZ measurement with ZZ operator



00	00	even	Left was 0
01	11	even	Left was 0
10	10	odd	Left was 1
11	01	odd	Left was 1

...analogous

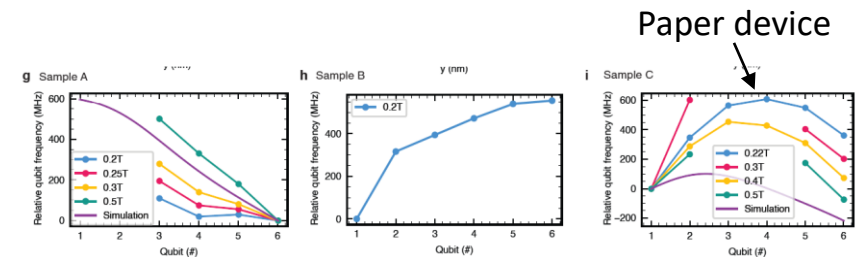
Calibration routines and single qubit benchmarking



...details well documented in SI

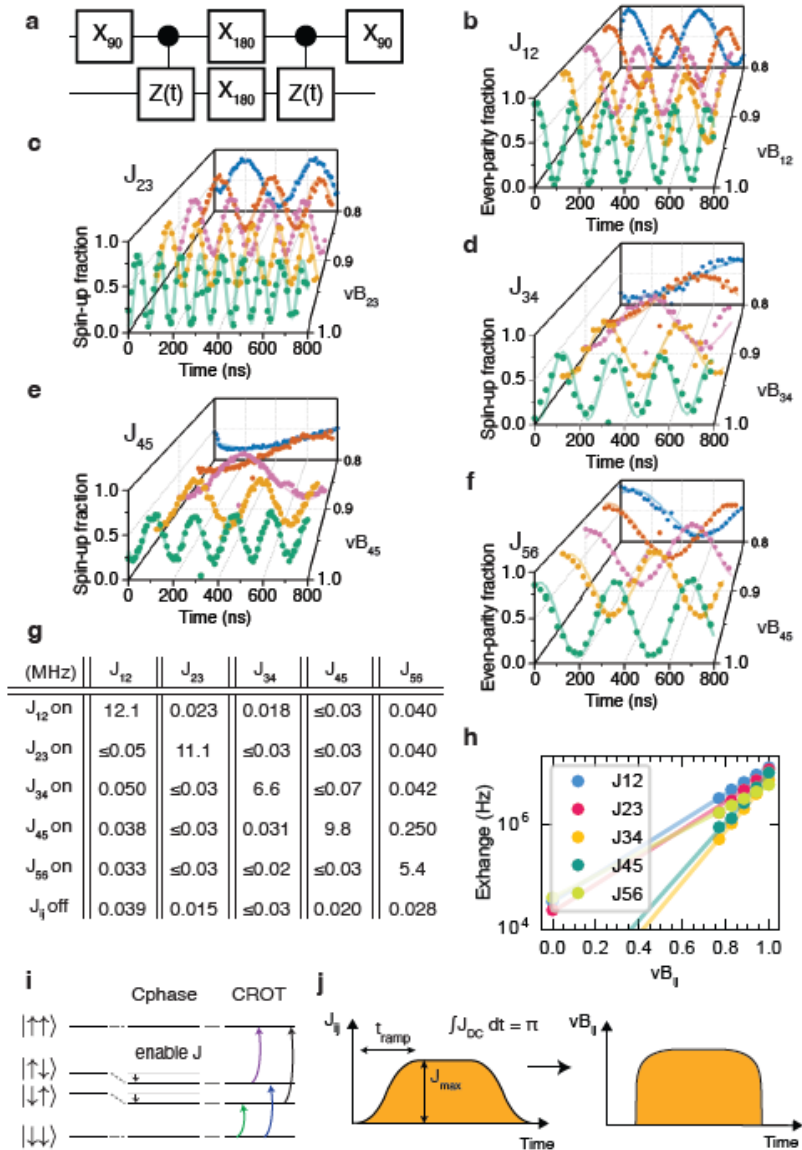
They calibrate every day everything but crosstalk
 They do full calibration 2xweek
 And specific calibrations when needed

Note that qubit frequencies are monotonically increasing...
 The magnet design is discussed in the SI
 (including simulations etc), but this looks a bit random...
Have we spotted a weakness in the shiny armour of the Vandersypen group?



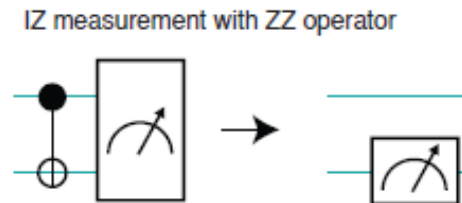
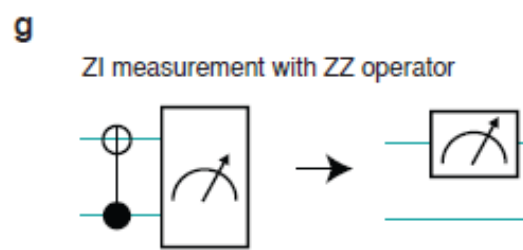
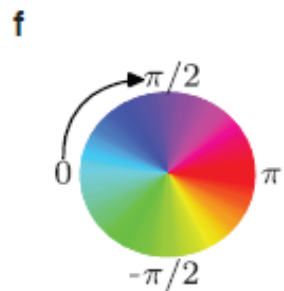
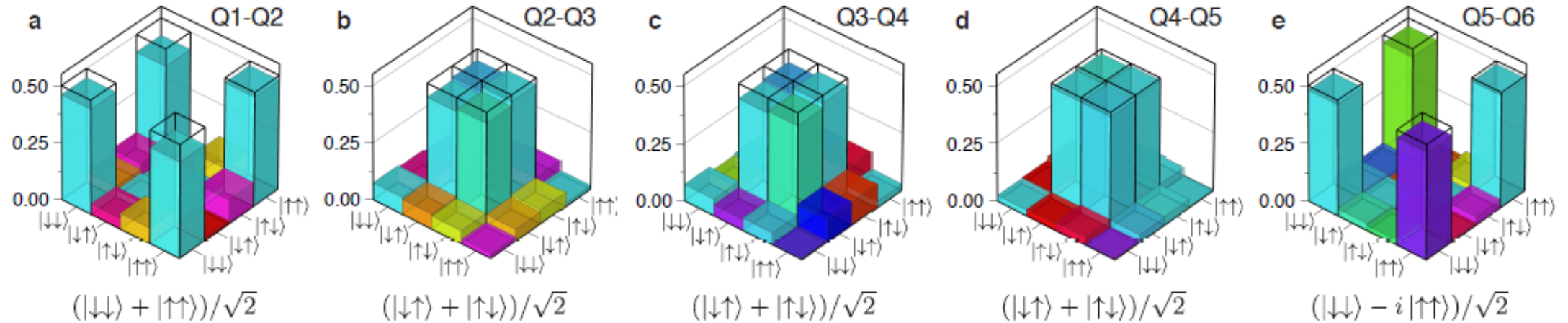
Paper device

Two qubit gates



- Use Crot gate:
 - > pulse target on equator
 - > Switch exchange on via barrier gate for time T
- Important: T and J need to be chosen such that the phase accumulated on target is π if control was up
Only then we call this Crot
- Pulse target back (should be 180 degrees rotated if control was up)
- Trick 1: Here they also use the barriers on the sides of the pair to push the wavefunctions closer together and increase J
- Trick 2: Use a smooth pulse on barrier (not rectangular pulse) to ensure adiabatic operation

Characterize two qubit: Bell-state tomography



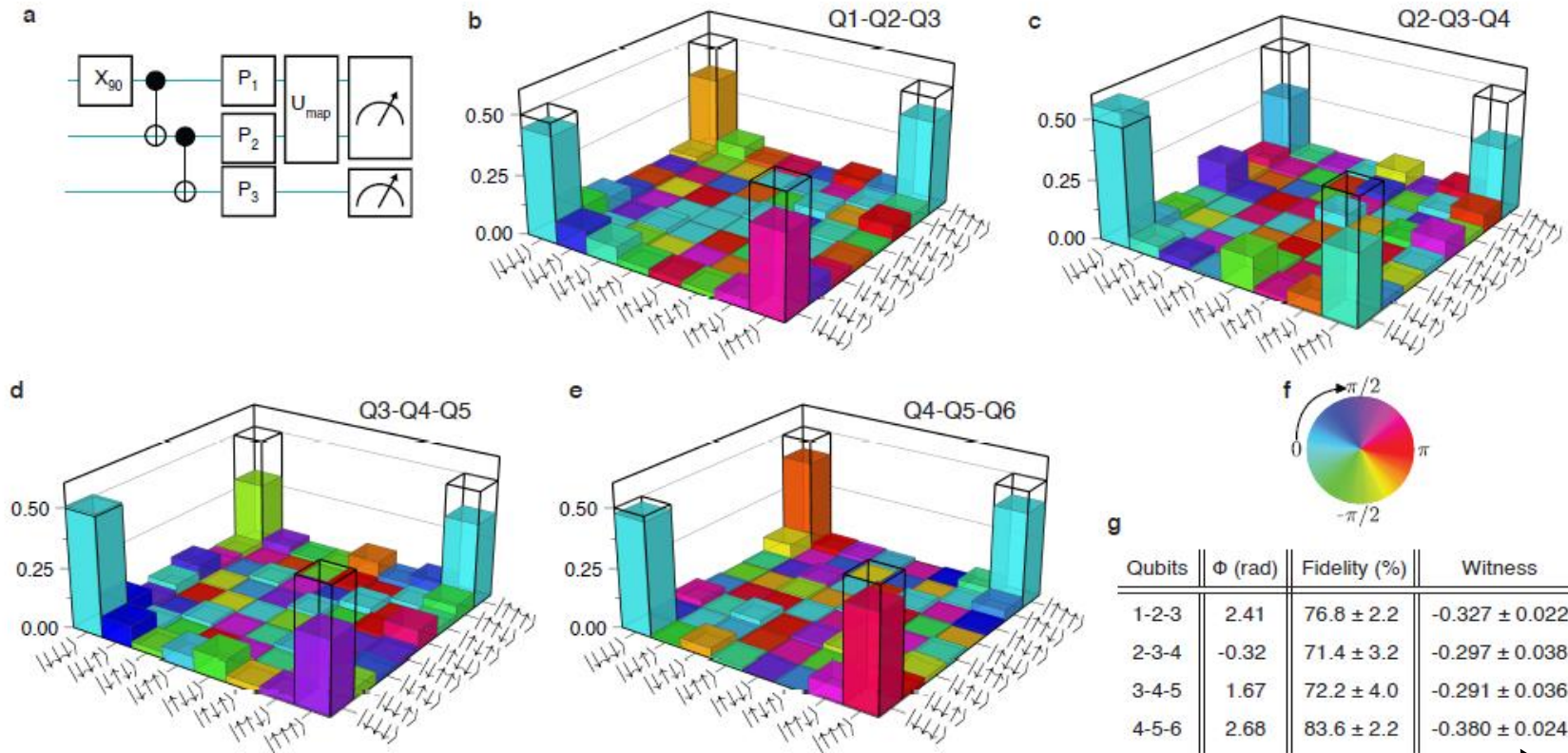
h

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5-6	94.1 ± 1.4	90.6 ± 3.6

Why not rdm benchmarking? -> Possible but costly...

↗
= measure for entanglement!

Characterize three qubit: GHZ states



$$|\psi_{\text{GHZ}}\rangle = (|000\rangle + e^{i\phi} |111\rangle)\sqrt{2},$$

= measure for entanglement!

Final comments:

- Probably the most advanced experiment in spin-qubits
- They mention issues with parallelization of gates/initialization (here they do everything consecutively, e.g. 1,2,3 and 4,5,6 initialization)
- They suspect there is an issue with heating... they see that in charge sensor and in the qubit performance
- I think they cannot control their magnets very well
- Valleys also seem to be an issue – especially when scaling up... bonus point for holes I would say!
- I encourage every new student to really try and understand the concepts here – it has almost everything you need and it is well documented in the SI/extended data
On that note, also check out this great review from last week on reflectometry (almost textbook level detailed explanation):

Probing quantum devices with radio-frequency reflectometry

Florian Vigneau,¹ Federico Fedele,¹ Anasua Chatterjee,² David Reilly,^{3,4} Ferdinand Kuemmeth,² M. Fernando Gonzalez-Zalba,^{5, a)} Edward Laird,^{6, b)} and Natalia Ares^{1, c)}

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(Dated: 23 February 2022)